



Data Sheet

January 2002

50A, 50V, 0.022 Ohm, Logic Level, N-Channel Power MOSFETs

These are logic-level N-channel power MOSFETs manufactured using the MegaFET process. This process, which uses feature sizes approaching those of LSI integrated circuits gives optimum utilization of silicon, resulting in outstanding performance. They were designed for use with logic-level (5V) driving sources in applications such as programmable controllers, automotive switching, switching regulators, switching converters, motor relay drivers and emitter switches for bipolar transistors. This performance is accomplished through a special gate oxide design which provides full rated conductance at gate bias in the 3V - 5V range, thereby facilitating true on-off power control directly from integrated circuit supply voltages.

Formerly developmental type TA09872.

Ordering Information

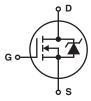
PART NUMBER	PACKAGE	BRAND
RFG50N05L	TO-247	RFG50N05L
RFP50N05L	TO-220AB	RFP50N05L

NOTE: When ordering, use the entire part number. Add the suffix 9A to obtain the TO-263AB variant in the tape and reel, i.e., RFP50N05L9A.

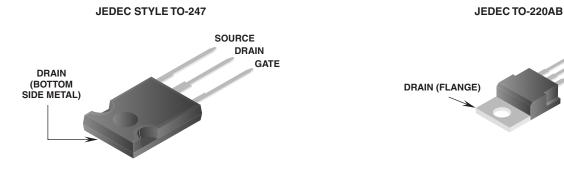
Features

- 50A, 50V
- r_{DS(ON)} = 0.022Ω
- UIS SOA Rating Curve (Single Pulse)
- · Design Optimized for 5V Gate Drive
- · Can be Driven Directly from CMOS, NMOS, TTL Circuits
- · Compatible with Automotive Drive Requirements
- SOA is Power Dissipation Limited
- Nanosecond Switching Speeds
- Linear Transfer Characteristics
- High Input Impedance
- Majority Carrier Device
- Related Literature
 - TB334 "Guidelines for Soldering Surface Mount Components to PC Boards"

Symbol



Packaging



SOURCE

GATE

Absolute Maximum Ratings $T_C = 25^{\circ}C$, Unless Otherwise Specified

	RFG50N05L	RFP50N05L	UNITS
Drain to Source Voltage (Note 1)	50	50	V
Drain to Gate Voltage (R_{GS} = 20k Ω) (Note 1) V _{DGR}	50	50	V
Continuous Drain CurrentI _D Pulsed Drain Current (Note 3)I _{DM}	50 130	50 130	A A
Gate to Source Voltage V_{GS}	±10	±10	V
Maximum Power Dissipation	110 0.88	110 0.88	W W/ ^o C
Single Pulse Avalanche Energy Rating	Refer to UIS	SOA Curve	-
Operating and Storage Temperature	-55 to 150	-55 to 150	°C
Maximum Temperature for Soldering Leads at 0.063in (1.6mm) from Case for 10sT _L Package Body for 10s, See Techbrief 334T _{pkg}	300 260	300 260	°C °C

CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.

NOTE:

1. $T_J = 25^{\circ}C$ to $125^{\circ}C$.

Electrical Specifications $T_C = 25^{\circ}C$, Unless Otherwise Specified

PARAMETER	SYMBOL	TEST CON	IDITIONS	MIN	ТҮР	MAX	UNITS
Drain to Source Breakdown Voltage	BV _{DSS}	$I_D = 250 \mu A$, $V_{GS} = 0V$ (Figure 10)		50	-	-	V
Gate Threshold Voltage	V _{GS(TH)}	$V_{GS} = V_{DS}$, $I_D = 250 \mu A$ (Figure 9)		1	-	2	V
Zero Gate Voltage Drain Current	I _{DSS}	DSS $V_{DS} = Rated BV_{DSS}, V_{GS} = 0$		-	-	25	μΑ
		$V_{DS} = 0.8 \text{ x}$ Rated BV _{DSS} , $V_{GS} = 0$, $T_C = 150^{\circ}C$		-	-	250	μΑ
Gate to Source Leakage Current	I _{GSS}	$V_{GS} = \pm 10V, V_{DS} = 0V$		-	-	±100	nA
Drain to Source On Resistance (Note 2)	rDS(ON)	$I_D = 50A, V_{GS} = 5V$ (Figure 7) $I_D = 50A, V_{GS} = 4V$		-	-	0.022	Ω
				-	-	0.027	Ω
Turn-On Time	t _(ON)	$V_{GS} = 5V, R_{GS} = 2.5\Omega, R_L = 1\Omega$ (Figures 12, 15, 16)		-	-	100	ns
Turn-On Delay Time	t _{D(ON)}			-	15	-	ns
Rise Time	t _r			-	50	-	ns
Turn-Off Delay Time	t _{D(OFF)}			-	50	-	ns
Fall Time	t _f			-	15	-	ns
Turn-Off Time	t _(OFF)			-	-	100	ns
Total Gate Charge	Q _{G(TOT)}	$V_{GS} = 0 \text{ to } 10V$ $V_{DD} = 40V, I_D = 50A$ $V_{GS} = 0 \text{ to } 5V$ $R_L = 0.8\Omega$ (Figures 17, 18)		-	-	140	nC
Gate Charge at 5V	Q _{G(5)}		-	-	80	nC	
Threshold Gate Charge	Q _{G(th})	$V_{GS} = 0 \text{ to } 1V$		-	-	6	nC
Thermal Resistance Junction to Case	R _{θJC}		·	-	-	1.14	°C/W
Thermal Resistance Junction to Ambient	R _{0JA}			-	-	80	°C/W

Source to Drain Diode Specifications

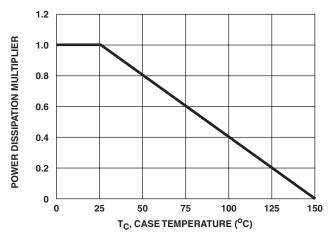
PARAMETER	SYMBOL	TEST CONDITIONS	MIN	ТҮР	MAX	UNITS
Source to Drain Diode Voltage (Note 2)	V _{SD}	I _{SD} = 50A	-	-	1.5	V
Diode Reverse Recovery Time	t _{rr}	I_{SD} = 50A, dI _{SD} /dt = 100A/µs	-	-	1.25	ns

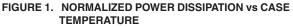
NOTES:

2. Pulsed: pulse duration = 300μ s maximum, duty cycle = 2%.

3. Repititive rating: pulse width limited by maximum junction temperature.

Typical Performance Curves





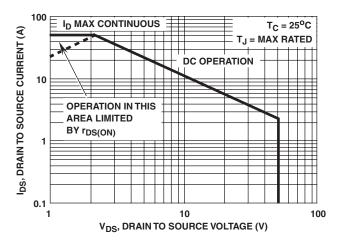
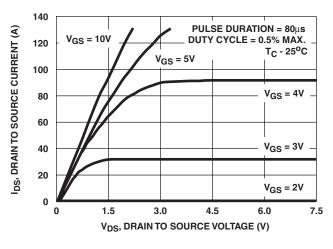


FIGURE 3. FORWARD BIAS SAFE OPERATING AREA





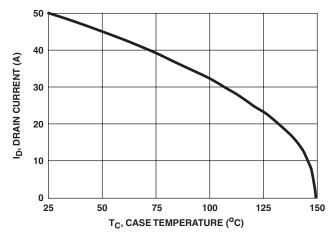
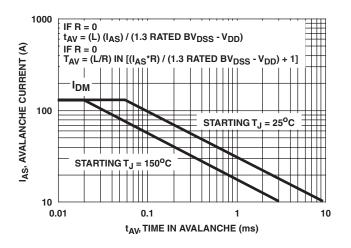


FIGURE 2. MAXIMUM CONTINUOUS DRAIN CURRENT vs CASE TEMPERATURE





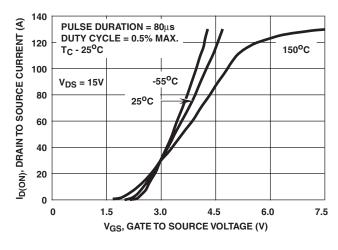
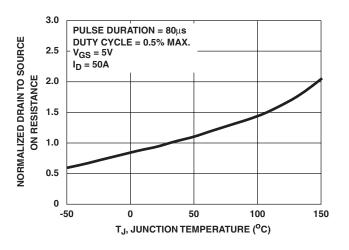


FIGURE 6. TRANSFER CHARACTERISTICS

Typical Performance Curves (Continued)





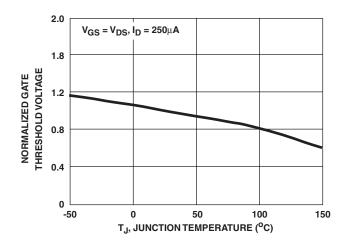


FIGURE 9. NORMALIZED GATE THRESHOLD VOLTAGE

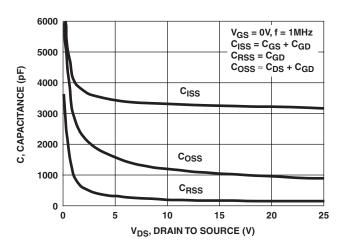


FIGURE 11. CAPACITANCE vs DRAIN TO SOURCE VOLTAGE

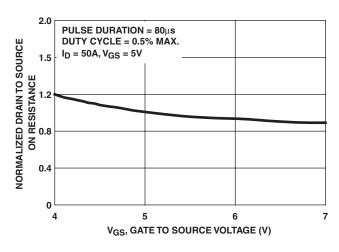


FIGURE 8. NORMALIZED DRAIN TO SOURCE ON RESISTANCE vs GATE VOLTAGE

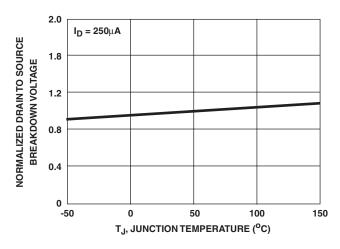
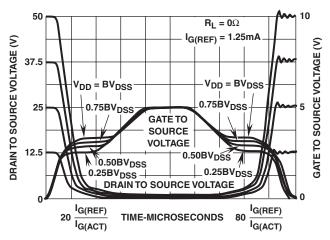


FIGURE 10. NORMALIZED DRAIN TO SOURCE BREAKDOWN VOLTAGE vs JUNCTION TEMPERATURE



NOTE: Refer to Fairchild Application Notes AN7254 and AN7260. FIGURE 12. NORMALIZED SWITCHING WAVEFORMS FOR CONSTANT GATE CURRENT

Test Circuits and Waveforms

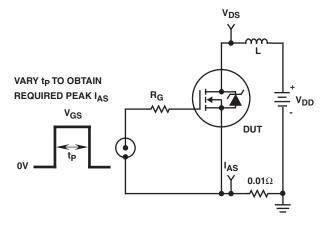


FIGURE 13. UNCLAMPED ENERGY TEST CIRCUIT

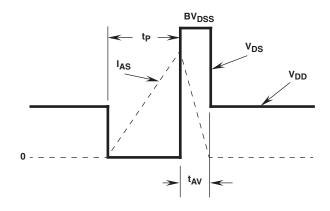


FIGURE 14. UNCLAMPED ENERGY WAVEFORMS

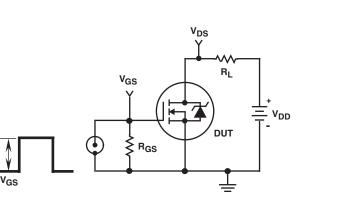


FIGURE 15. SWITCHING TIME TEST CIRCUIT

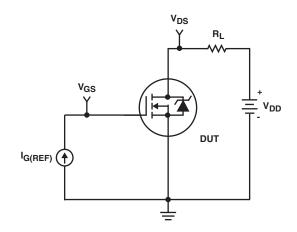


FIGURE 17. GATE CHARGE TEST CIRCUIT

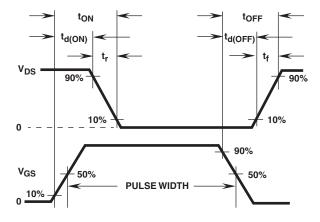


FIGURE 16. RESISTIVE SWITCHING WAVEFORMS

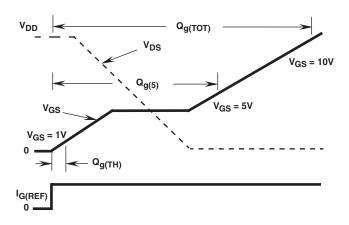


FIGURE 18. GATE CHARGE WAVEFORMS

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PRODUCT STATUS DEFINITIONS

Definition of Term s

Product Status	Definition
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